

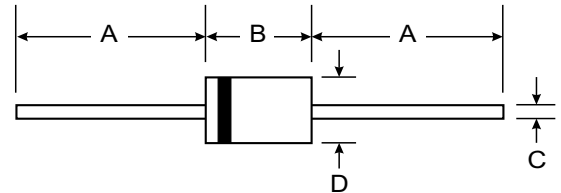
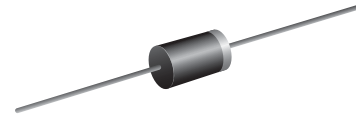
**VOLTAGE RANGE: 150 - 200V**  
**CURRENT: 5.0 A**

### Features

- Schottky Barrier Chip
- Ideally Suited for Automatic Assembly
- Low Power Loss, High Efficiency
- For Use in Low Voltage Application
- Guard Ring Die Construction
- Plastic Case Material has UL Flammability Classification Rating 94V-O

### Mechanical Data

- Case: DO-201AD, Molded Plastic
- Terminals: Plated Leads Solderable per MIL-STD-202, Method 208
- Polarity: Cathode Band
- Weight: 1.2 grams (approx.)
- Mounting Position: Any
- Marking: Type Number



DO-201AD		
Dim	Min	Max
A	25.40	—
B	7.20	9.50
C	1.20	1.30
D	4.80	5.30
All Dimensions in mm		

### Maximum Ratings and Electrical Characteristics $T_A = 25^\circ\text{C}$ unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic	Symbol	SR5150	SR5200	Unit
Maximum repetitive peak reverse voltage	$V_{RRM}$	150	200	Volts
Maximum RMS voltage	$V_{RMS}$	105	150	Volts
Maximum DC blocking voltage	$V_{DC}$	150	200	Volts
Maximum average forward rectified current at $T_L$ (see fig.1)	$I_{(AV)}$	5.0		Amps
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	$I_{FSM}$	150.0		Amps
Maximum instantaneous forward voltage at 5.0A	$V_F$	0.85	0.95	Volts
Maximum DC reverse current $T_A=25^\circ\text{C}$ at rated DC blocking voltage $T_A=100^\circ\text{C}$	$I_R$	0.2 2.0		mA
Typical junction capacitance (NOTE 1)	$C_J$	200		pF
Typical thermal resistance (NOTE 2)	$R_{\theta JA}$	50.0		$^\circ\text{C}/\text{W}$
Operating junction temperature range	$T_J$	-50 to +150		$^\circ\text{C}$
Storage temperature range	$T_{STG}$	-50 to +150		$^\circ\text{C}$

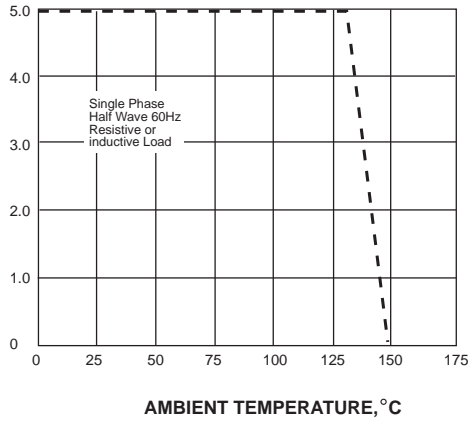
**Note:** 1. Measured at 1MHz and applied reverse voltage of 4.0V D.C.  
 2. P.C.B. mounted with 0.2x0.25x5.0mm copper pad areas



**RATINGS AND CHARACTERISTIC CURVES SR5150 THRU SR5200**

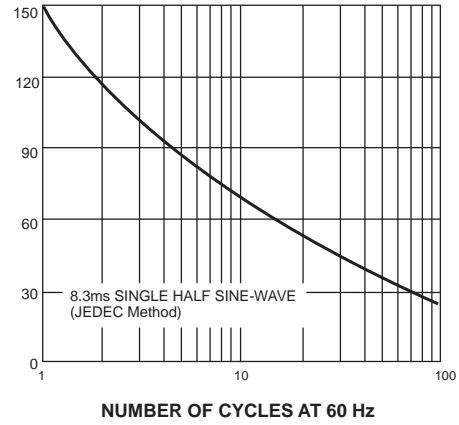
AVERAGE FORWARD RECTIFIED CURRENT, AMPERES

FIG. 1- FORWARD CURRENT DERATING CURVE



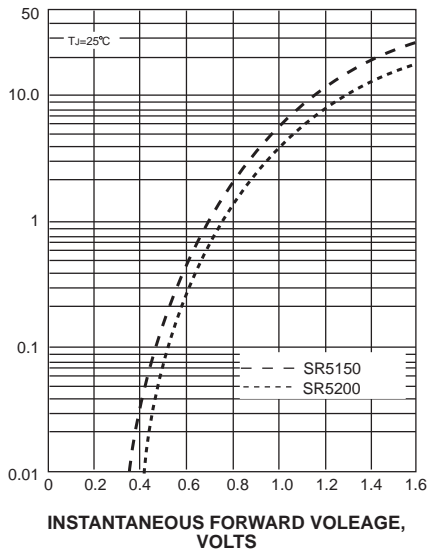
PEAK FORWARD SURGE CURRENT, AMPERES

FIG. 2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT



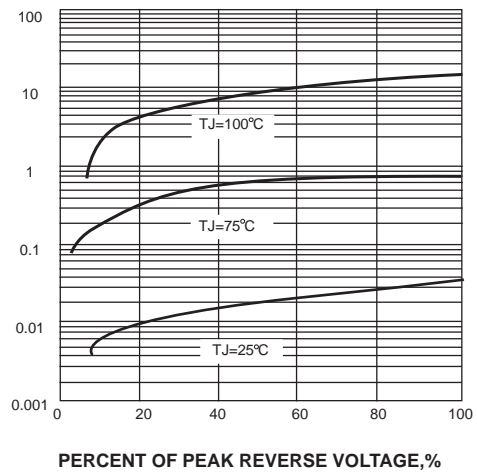
INSTANTANEOUS FORWARD CURRENT, AMPERES

FIG. 3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS



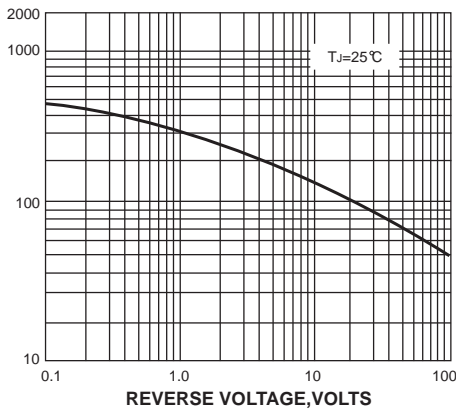
INSTANTANEOUS REVERSE CURRENT, MILLIAMPERES

FIG. 4-TYPICAL REVERSE CHARACTERISTICS



JUNCTION CAPACITANCE, pF

FIG. 5-TYPICAL JUNCTION CAPACITANCE



TRANSIENT THERMAL IMPEDANCE, °C/W

FIG. 6-TYPICAL TRANSIENT THERMAL IMPEDANCE

